

# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic  |                 |  | Symbol             | Value        | Unit |
|---|-----------------|--|--------------------|--------------|------|
| Drain-Source Voltage                                    |                 |  | V <sub>DSS</sub>   | -20          | V    |
| Gate-Source Voltage                                     |                 |  | Vgss               | -12          | V    |
| Continuous Drain Current (Note 5) V <sub>GS</sub> = -8V | Steady<br>State | T <sub>A</sub> = +25°C<br>T <sub>A</sub> = +70°C | ID                 | -3.4<br>-2.7 | A    |
| Continuous Drain Current (Note 5) $V_{GS}$ = -4.5V      | Steady<br>State | T <sub>A</sub> = +25°C<br>T <sub>A</sub> = +70°C | ID                 | -3.0<br>-2.4 | А    |
| Pulsed Drain Current (Note 6)                           |                 |  | Ідм                | -13          | А    |
| Human Body Model (HBM)                                  |                 |  | V <sub>(ESD)</sub> | 4            | kV   |

# **Thermal Characteristics**

| Characteristic   | Symbol           | Value       | Unit |
|--|------------------|-------------|------|
| Power Dissipation (Note 7)   | PD               | 0.81        | W    |
| Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7) | R <sub>0JA</sub> | 155.4       | °C/W |
| Power Dissipation (Note 5)   | PD               | 1.4         | W    |
| Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5) | R <sub>0JA</sub> | 90.4        | °C/W |
| Operating and Storage Temperature Range                                | TJ, TSTG         | -55 to +150 | °C   |

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                             | Symbol              | Min  | Тур  | Max  | Unit | Test Condition   |  |
|--|---------------------|------|------|------|------|--|--|
| OFF CHARACTERISTICS (Note 8)               |                     |      |      |      |      |  |  |
| Drain-Source Breakdown Voltage             | BVDSS               | -20  | —    | —    | V    | $V_{GS} = 0V, I_D = -250\mu A$                                   |  |
| Zero Gate Voltage Drain Current TJ = +25°C | IDSS                | _    | —    | -100 | nA   | V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V                     |  |
| Gate-Source Leakage                        | lgss                | _    | —    | -50  | nA   | V <sub>GS</sub> = -12V, V <sub>DS</sub> = 0V                     |  |
| ON CHARACTERISTICS (Note 8)                | •                   |      | •    | •    | •    | ·  |  |
| Gate Threshold Voltage                     | V <sub>GS(TH)</sub> | -0.7 | -0.9 | -1.2 | V    | $V_{DS} = V_{GS}$ , $I_D = -250 \mu A$                           |  |
| Static Drain-Source On-Resistance          |                     | —    | 64   | 78   | ·mΩ  | VGS = -8V, ID = -0.5A  |  |
|  | Descen              | —    | 77   | 100  |      | VGS = -4.5V, ID = -0.5A  |  |
|  | Rds(on)             | _    | 113  | 165  |      | $V_{GS} = -2.5V, I_D = -0.5A$                                    |  |
|  |                     | _    | 188  | 600  |      | $V_{GS} = -1.8V, I_D = -0.1A$                                    |  |
| Diode Forward Voltage                      | Vsd                 |      | -0.7 | -1.0 | V    | VGS = 0V, IS = -0.5A   |  |
| Reverse Recovery Charge                    | Qrr                 |      | 1.3  | —    | nC   | V <sub>DD</sub> = -10V, I <sub>F</sub> = -1A,                    |  |
| Reverse Recovery Time                      | t <sub>RR</sub>     | _    | 7.7  | —    | ns   | di/dt = 100A/µs  |  |
| DYNAMIC CHARACTERISTICS (Note 9)           |                     |      |      |      |      | -  |  |
| Input Capacitance                          | Ciss                | —    | 152  | 228  |      | $V_{DS} = -10V, V_{GS} = 0V,$<br>f = 1MHz                        |  |
| Output Capacitance                         | Coss                | _    | 78   | 117  | pF   |  |  |
| Reverse Transfer Capacitance               | Crss                | _    | 4.3  | 6.4  |      |  |  |
| Series Gate Resistance                     | R <sub>G</sub>      | _    | 21   | 31   | Ω    | $f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$                       |  |
| Total Gate Charge                          | Qg                  | _    | 1.1  | 1.6  |      |  |  |
| Gate-Source Charge                         | Qgs                 |      | 0.2  | _    | nC   | $V_{GS} = -4.5V, V_{DS} = -10V,$<br>$I_{D} = -0.5A$              |  |
| Gate-Drain Charge                          | Q <sub>gd</sub>     |      | 0.2  | _    | nC   |  |  |
| Gate Charge at VTH                         | Qg(th)              |      | 3.6  | _    |      |  |  |
| Turn-On Delay Time                         | tD(ON)              | _    | 4.1  | 6.1  |      | $V_{DS} = -10V, V_{GS} = -4.5V,$<br>$R_G = 2\Omega, I_D = -0.5A$ |  |
| Turn-On Rise Time                          | tR                  | _    | 5.6  | —    | 1    |  |  |
| Turn-Off Delay Time                        | t <sub>D(OFF)</sub> | _    | 9.5  | 14.2 | ns   |  |  |
| Turn-Off Fall Time                         | tF                  |      | 4.6  | _    | 1    |  |  |

5. Device mounted on FR-4 material with 1inch<sup>2</sup> (6.45cm<sup>2</sup>), 2oz. (0.071mm thick) Cu.

6. Repetitive rating, pulse width limited by junction temperature.

7. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.

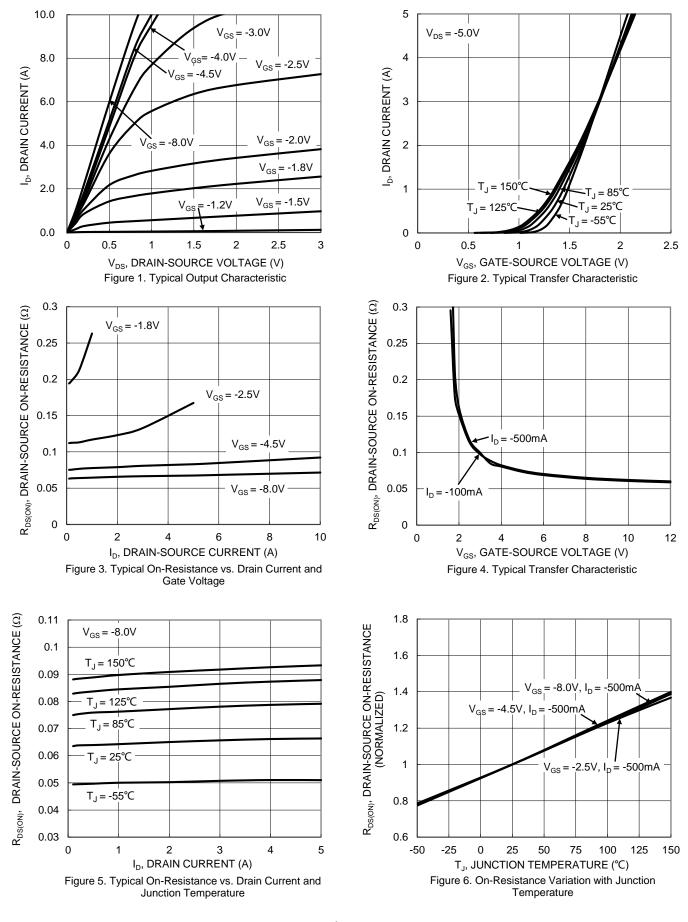
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.

Notes:



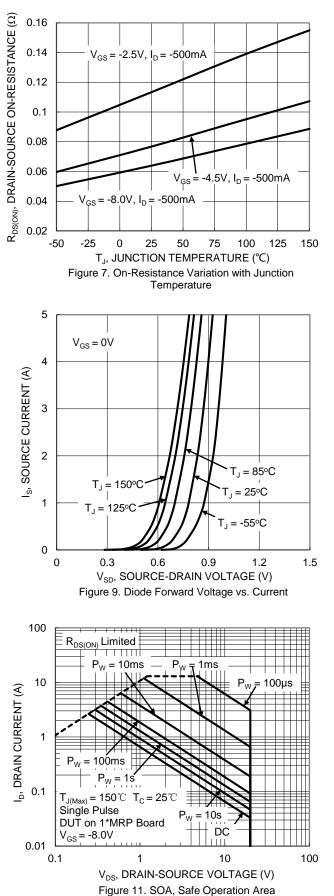
## DMP2078LCA3

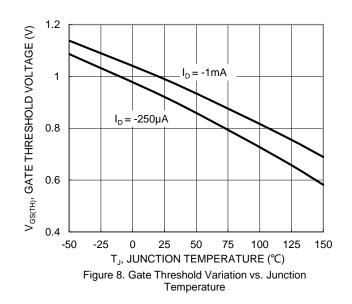


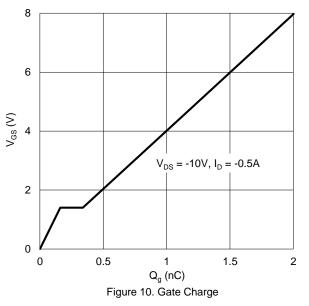
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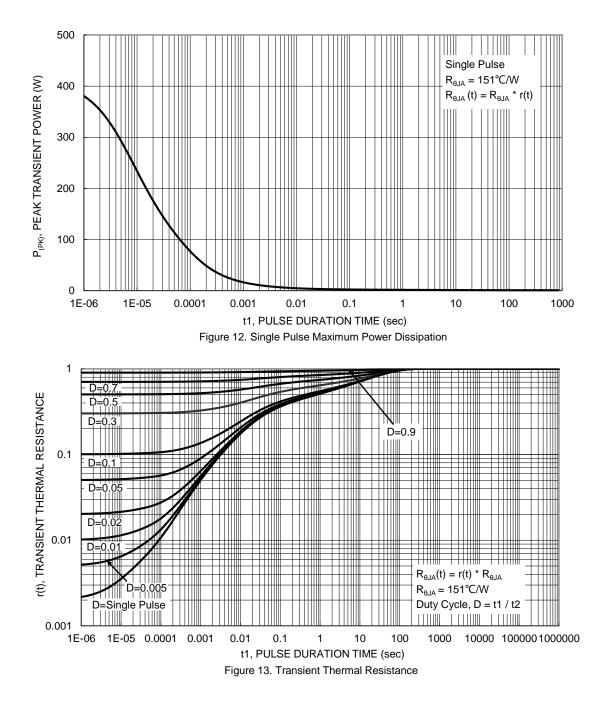
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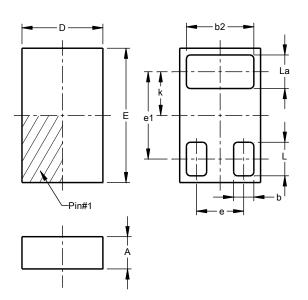




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

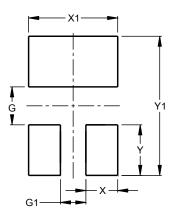




|                      | X4-DSN1006-3 |      |       |  |  |  |
|----------------------|--------------|------|-------|--|--|--|
| Dim                  | Min          | Max  | Тур   |  |  |  |
| Α                    | 0.18         | 0.22 | 0.20  |  |  |  |
| b                    | 0.14         | 0.16 | 0.15  |  |  |  |
| b2                   | 0.49         | 0.51 | 0.50  |  |  |  |
| D                    | 0.56         | 0.64 | 0.60  |  |  |  |
| E                    | 0.96         | 1.04 | 1.00  |  |  |  |
| е                    |              |      | 0.35  |  |  |  |
| e1                   |              |      | 0.65  |  |  |  |
| k                    |              |      | 0.325 |  |  |  |
| L                    | 0.24         | 0.26 | 0.25  |  |  |  |
| La                   | 0.24         | 0.26 | 0.25  |  |  |  |
| All Dimensions in mm |              |      |       |  |  |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



#### X4-DSN1006-3

| Dimensions | Value<br>(in mm) |
|------------|------------------|
| G          | 0.40             |
| G1         | 0.20             |
| Х          | 0.15             |
| X1         | 0.50             |
| Y          | 0.25             |
| Y1         | 0.90             |



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